APPLICATION DATA SHEET

Electronic Version v14 Stylesheet Version v14.0

> Title of Invention

High Density Metal Capacitor Using Via Etch Stopping Layer as Field Dielectric in Dual-Damascence Interconnect Process

Application Type:

regular, utility

Attorney Docket Number: 1875.0230001/JDE

Correspondence address:

Customer Number:

26111

26111

Continuing Data:

This is a Continuation of US application number 09/753,664, filed 2001-01-04.

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